BUT11F/11AF

# FAIRCHILD

## BUT11F/11AF

## High Voltage Power Switching Applications



## **NPN Silicon Transistor**

1.Base 2.Collector 3.Emitter

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: BUT11F	850	V
	: BUT11AF	1000	V
V <sub>CEO</sub> Collector-Emitter Voltage			
	: BUT11F	400	V
	: BUT11AF	450	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	5	А
I <sub>CP</sub>	*Collector Current (Pulse)	10	А
B	Base Current (DC)	2	А
I <sub>BP</sub>	*Base Current (Pulse)	4	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W
Tj	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

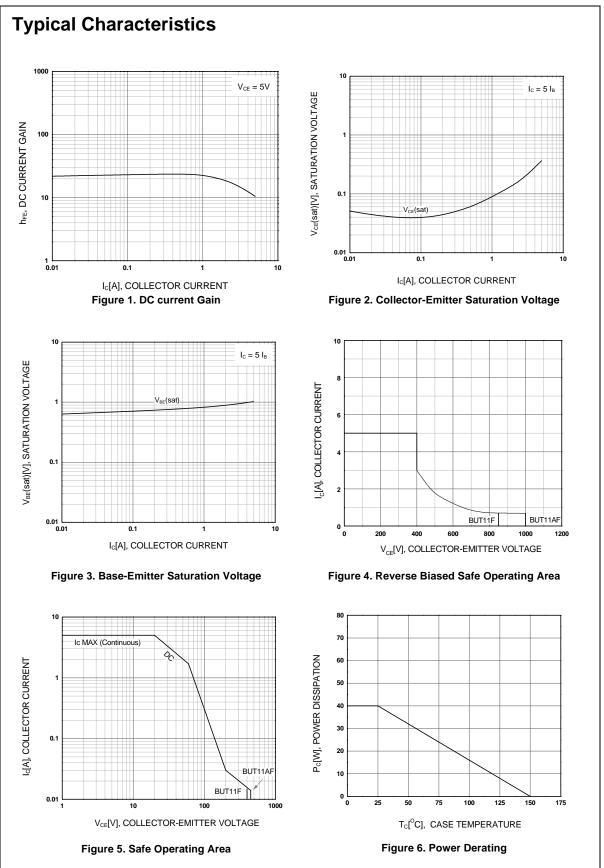
## Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage : BUT11F	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 0$	400			V
	: BUT11AF	$I_{\rm C} = 10011$ A, $I_{\rm B} = 0$	400			V
I <sub>CES</sub>	Collector Cut-off Current					
	: BUT11F	$V_{CE} = 850V, V_{BE} = 0$			1	mA
	: BUT11AF	$V_{CE} = 1000V, V_{BE} = 0$			1	mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = 9V, I_{C} = 0$			10	mA
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage					
	: BUT11F	$I_{\rm C} = 3A, I_{\rm B} = 0.6A$			1.5	V
	: BUT11AF	I <sub>C</sub> = 2.5A, I <sub>B</sub> = 0.5A			1.5	V
V <sub>BF</sub> (sat)	Base-Emitter Saturation Voltage					
	: BUT11F	$I_{\rm C} = 3A, I_{\rm B} = 0.6A$			1.3	V
	: BUT11AF	$I_{\rm C} = 2.5 {\rm A}, I_{\rm B} = 0.5 {\rm A}$			1.3	V
t <sub>ON</sub>	Turn ON Time	$V_{CC} = 250V, I_{C} = 2.5A$			1	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 0.5A$			4	μs
t <sub>F</sub>	Fall Time	$R_L = 100\Omega$			0.8	μs

\* Pulsed: pulsed duration =  $300\mu s$ , duty cycle = 1.5%

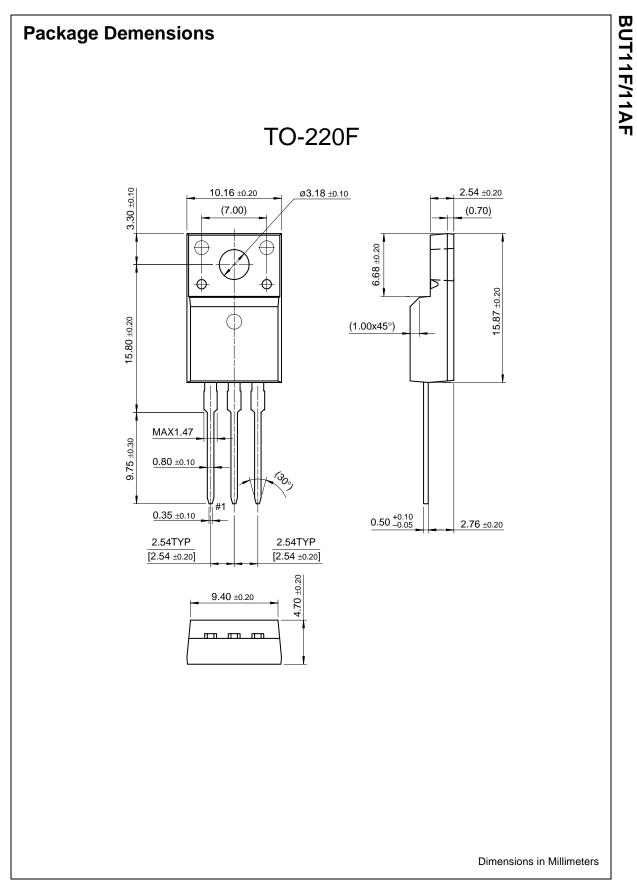
### Thermal Characteristics $T_{C}=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Тур	Max	Units
R <sub>θjC</sub> Thermal Resistance, Junction to Case			3.125	°C/W



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